

# 74HC137

## 3-to-8 line decoder, demultiplexer with address latches; inverting

Rev. 4 — 23 December 2015

Product data sheet

### 1. General description

The 74HC137 is a high-speed Si-gate CMOS device and is pin compatible with low power Schottky TTL (LSTTL). The 74HC137 is specified in compliance with JEDEC standard no. 7A.

The 74HC137 is a 3-to-8 line decoder, demultiplexer with latches at the three address inputs ( $A_n$ ). The 74HC137 essentially combines the 3-to-8 decoder function with a 3-bit storage latch. When the latch is enabled ( $\overline{LE} = \text{LOW}$ ), the 74HC137 acts as a 3-to-8 active LOW decoder. When the latch enable ( $\overline{LE}$ ) goes from LOW-to-HIGH, the last data present at the inputs before this transition, is stored in the latches. Further address changes are ignored as long as  $\overline{LE}$  remains HIGH.

The output enable input ( $\overline{E}1$  and  $E2$ ) controls the state of the outputs independent of the address inputs or latch operation. All outputs are HIGH unless  $\overline{E}1$  is LOW and  $E2$  is HIGH.

The 74HC137 is ideally suited for implementing non-overlapping decoders in 3-state systems and strobed (stored address) applications in bus oriented systems.

### 2. Features and benefits

- Combines 3-to-8 decoder with 3-bit latch
- Multiple input enable for easy expansion or independent controls
- Active LOW mutually exclusive outputs
- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+80\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$ .

### 3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC137D	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC137DB	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1



4. Functional diagram

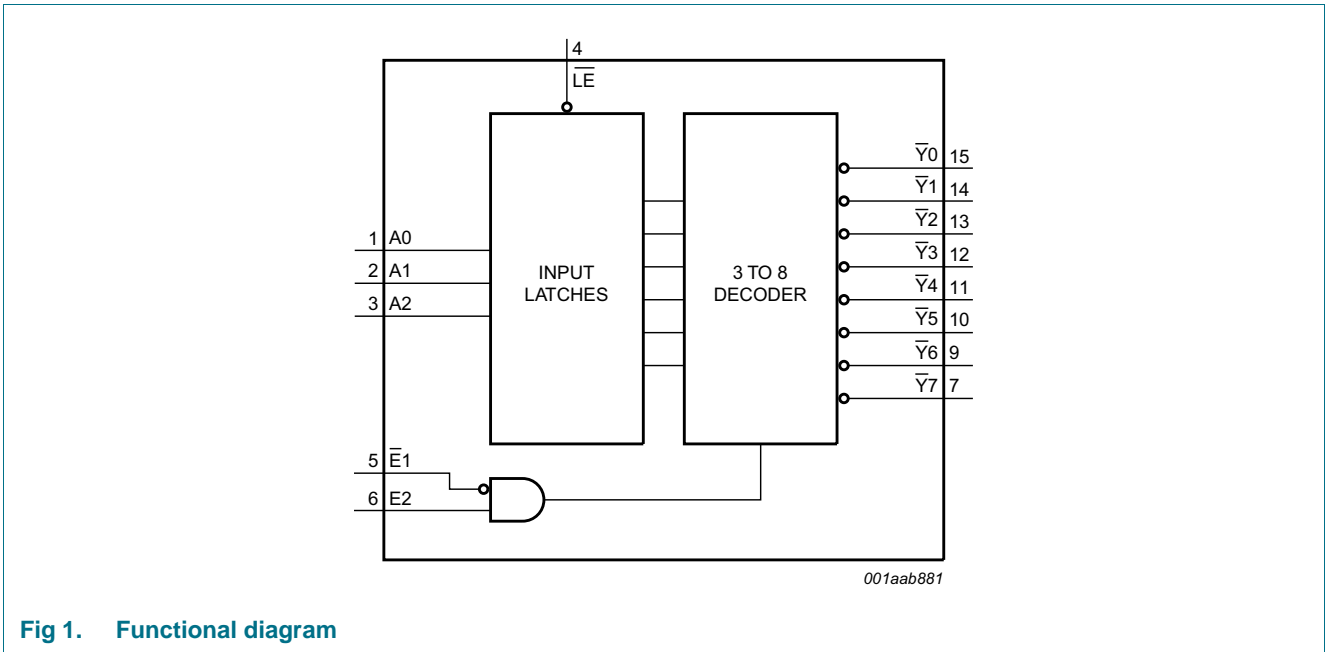


Fig 1. Functional diagram

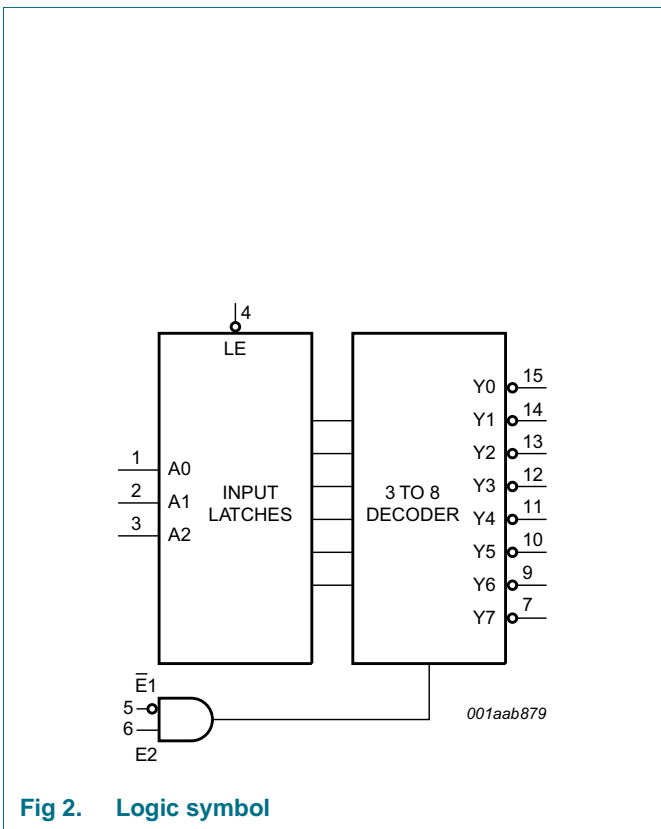


Fig 2. Logic symbol

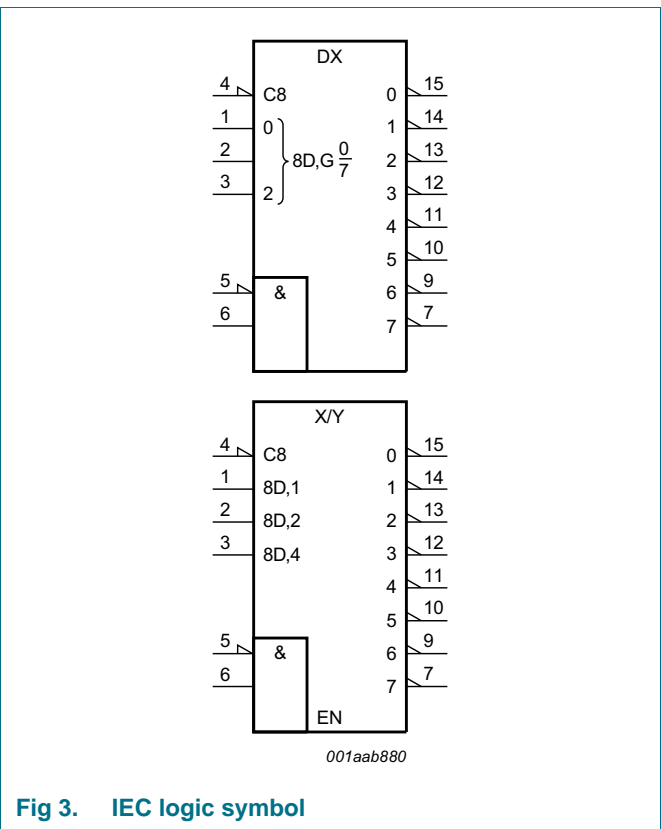


Fig 3. IEC logic symbol

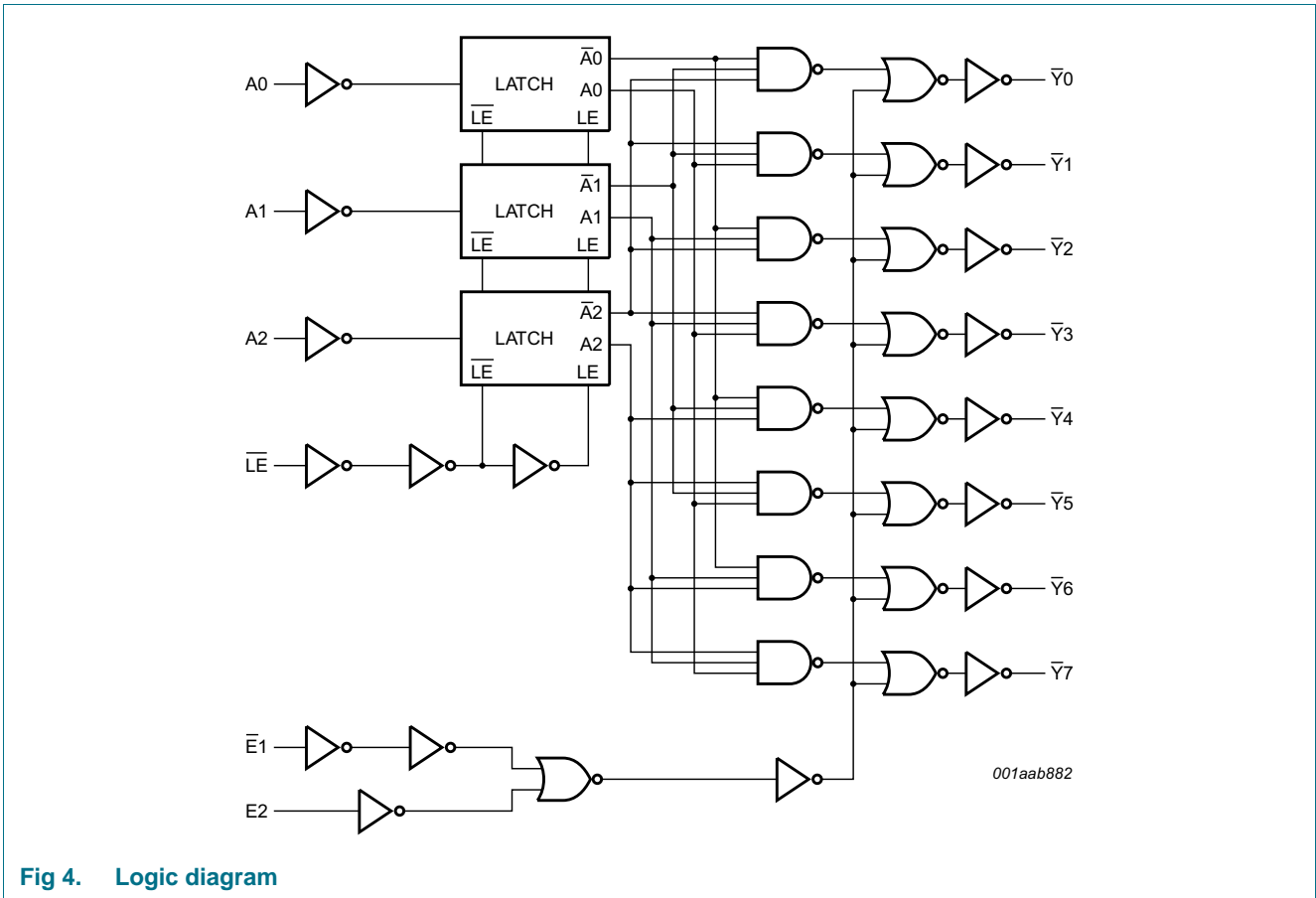


Fig 4. Logic diagram

## 5. Pinning information

### 5.1 Pinning

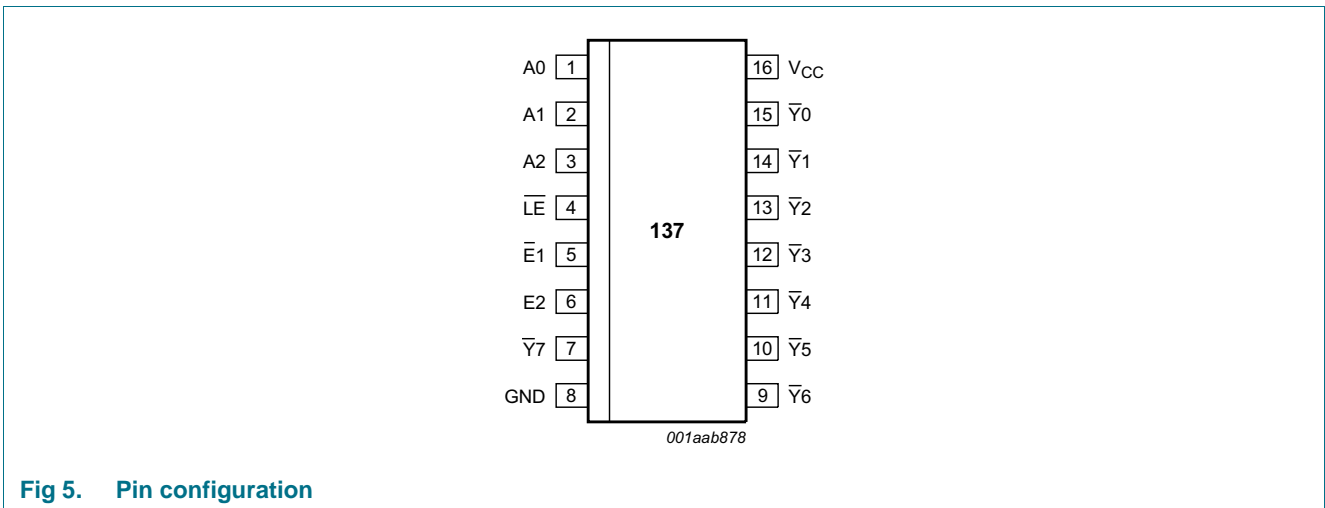


Fig 5. Pin configuration

## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
A0	1	data input 0
A1	2	data input 1
A2	3	data input 2
$\overline{\text{LE}}$	4	latch enable input (active LOW)
$\overline{\text{E1}}$	5	data enable input 1 (active LOW)
E2	6	data enable input 2 (active HIGH)
$\overline{\text{Y7}}$	7	multiplexer output 7
GND	8	ground (0 V)
$\overline{\text{Y6}}$	9	multiplexer output 6
$\overline{\text{Y5}}$	10	multiplexer output 5
$\overline{\text{Y4}}$	11	multiplexer output 4
$\overline{\text{Y3}}$	12	multiplexer output 3
$\overline{\text{Y2}}$	13	multiplexer output 2
$\overline{\text{Y1}}$	14	multiplexer output 1
$\overline{\text{Y0}}$	15	multiplexer output 0
V <sub>CC</sub>	16	positive supply voltage

## 6. Functional description

### 6.1 Function table

Table 3. Function table<sup>[1]</sup>

Enable			Input			Output							
$\overline{\text{LE}}$	$\overline{\text{E1}}$	E2	A0	A1	A2	$\overline{\text{Y0}}$	$\overline{\text{Y1}}$	$\overline{\text{Y2}}$	$\overline{\text{Y3}}$	$\overline{\text{Y4}}$	$\overline{\text{Y5}}$	$\overline{\text{Y6}}$	$\overline{\text{Y7}}$
H	L	H	X	X	X	stable							
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	L	X	X	X	H	H	H	H	H	H	H	H
L	L	H	L	L	L	L	H	H	H	H	H	H	H
			H	L	L	H	L	H	H	H	H	H	H
			L	H	L	H	H	L	H	H	H	H	H
			H	H	L	H	H	H	L	H	H	H	H
			L	L	H	H	H	H	H	L	H	H	H
			H	L	H	H	H	H	H	H	L	H	H
			L	H	H	H	H	H	H	H	H	L	H
			H	H	H	H	H	H	H	H	H	H	H

- [1] H = HIGH voltage level;  
 L = LOW voltage level;  
 X = don't care.

## 7. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
$I_{IK}$	input diode current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_{OK}$	output diode current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_O$	output source or sink current	$V_O = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$	-	$\pm 25$	mA
$I_{CC}$	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	power dissipation	SO16 and SSOP16 packages <a href="#">[1]</a>	-	500	mW

- [1] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.  
 For SSOP14 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CC}$	supply voltage		2.0	5.0	6.0	V
$V_I$	input voltage		0	-	$V_{CC}$	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0\text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5\text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0\text{ V}$	-	-	83	ns/V
$T_{amb}$	ambient temperature		-40	-	+125	°C

## 9. Static characteristics

**Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	V
		I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±0.1	μA
		V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	8.0	μA
C <sub>I</sub>	input capacitance		-	3.5	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 4.5 V	3.84	-	-	V
I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V		5.34	-	-	V	

**Table 6. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	80	μA
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		-		
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		-		
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	160	μA

## 10. Dynamic characteristics

**Table 7. Dynamic characteristics**  
*GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF.*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
t <sub>pd</sub>	propagation delay	An to $\overline{Y}_n$ ; see <a href="#">Figure 6</a> [1]				
		V <sub>CC</sub> = 2.0 V	-	58	180	ns
		V <sub>CC</sub> = 4.5 V	-	21	36	ns
		V <sub>CC</sub> = 6.0 V	-	17	31	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	18	-	ns
		$\overline{LE}$ to $\overline{Y}_n$ ; see <a href="#">Figure 7</a>				
		V <sub>CC</sub> = 2.0 V	-	55	190	ns
		V <sub>CC</sub> = 4.5 V	-	20	38	ns
		V <sub>CC</sub> = 6.0 V	-	16	32	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	17	-	ns
		$\overline{E1}$ to $\overline{Y}_n$ ; see <a href="#">Figure 7</a>				
		V <sub>CC</sub> = 2.0 V	-	50	145	ns
		V <sub>CC</sub> = 4.5 V	-	18	29	ns
		V <sub>CC</sub> = 6.0 V	-	14	25	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	15	-	ns
		E2 to $\overline{Y}_n$ ; see <a href="#">Figure 6</a>	V <sub>CC</sub> = 2.0 V	-	50	145
V <sub>CC</sub> = 4.5 V	-		18	29	ns	
V <sub>CC</sub> = 6.0 V	-		14	25	ns	
V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-		15	-	ns	
t <sub>t</sub>	transition time	see <a href="#">Figure 6</a> [2]				
		V <sub>CC</sub> = 2.0 V	-	19	75	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	ns
t <sub>w</sub>	pulse width	$\overline{LE}$ HIGH; see <a href="#">Figure 8</a>				
		V <sub>CC</sub> = 2.0 V	50	11	-	ns
		V <sub>CC</sub> = 4.5 V	10	4	-	ns
		V <sub>CC</sub> = 6.0 V	9	3	-	ns
t <sub>su</sub>	set-up time	An to $\overline{LE}$ ; see <a href="#">Figure 8</a>				
		V <sub>CC</sub> = 2.0 V	50	3	-	ns
		V <sub>CC</sub> = 4.5 V	10	1	-	ns
		V <sub>CC</sub> = 6.0 V	9	1	-	ns
t <sub>h</sub>	hold time	An to $\overline{LE}$ ; see <a href="#">Figure 8</a>				
		V <sub>CC</sub> = 2.0 V	30	3	-	ns
		V <sub>CC</sub> = 4.5 V	6	1	-	ns
		V <sub>CC</sub> = 6.0 V	5	1	-	ns
C <sub>PD</sub>	power dissipation capacitance	V <sub>I</sub> = GND to V <sub>CC</sub> [3]	-	57	-	pF



**Table 7. Dynamic characteristics ...continued**  
*GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF.*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>						
$t_{pd}$	propagation delay	An to $\bar{Y}_n$ ; see <a href="#">Figure 6</a> [1]				
		$V_{CC} = 2.0$ V	-	-	225	ns
		$V_{CC} = 4.5$ V	-	-	45	ns
		$V_{CC} = 6.0$ V	-	-	38	ns
		$\bar{LE}$ to $\bar{Y}_n$ ; see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	-	240	ns
		$V_{CC} = 4.5$ V	-	-	48	ns
		$V_{CC} = 6.0$ V	-	-	41	ns
		$\bar{E}1$ to $\bar{Y}_n$ ; see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	-	180	ns
		$V_{CC} = 4.5$ V	-	-	36	ns
		$V_{CC} = 6.0$ V	-	-	31	ns
		$E2$ to $\bar{Y}_n$ ; see <a href="#">Figure 6</a>				
$V_{CC} = 2.0$ V	-	-	180	ns		
$V_{CC} = 4.5$ V	-	-	36	ns		
$V_{CC} = 6.0$ V	-	-	31	ns		
$t_t$	transition time	see <a href="#">Figure 6</a> [2]				
		$V_{CC} = 2.0$ V	-	-	95	ns
		$V_{CC} = 4.5$ V	-	-	19	ns
		$V_{CC} = 6.0$ V	-	-	16	ns
$t_w$	pulse width	$\bar{LE}$ HIGH; see <a href="#">Figure 8</a>				
		$V_{CC} = 2.0$ V	65	-	-	ns
		$V_{CC} = 4.5$ V	13	-	-	ns
		$V_{CC} = 6.0$ V	11	-	-	ns
$t_{su}$	set-up time	An to $\bar{LE}$ ; see <a href="#">Figure 8</a>				
		$V_{CC} = 2.0$ V	65	-	-	ns
		$V_{CC} = 4.5$ V	13	-	-	ns
		$V_{CC} = 6.0$ V	11	-	-	ns
$t_h$	hold time	An to $\bar{LE}$ ; see <a href="#">Figure 8</a>				
		$V_{CC} = 2.0$ V	40	-	-	ns
		$V_{CC} = 4.5$ V	8	-	-	ns
		$V_{CC} = 6.0$ V	7	-	-	ns

**Table 7. Dynamic characteristics ...continued**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$ .

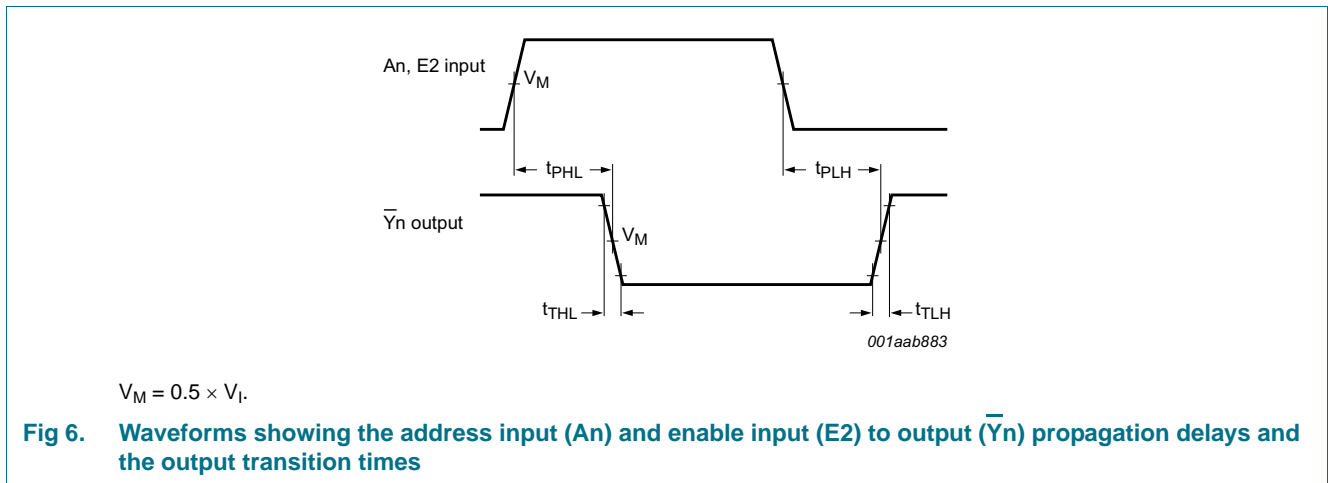
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = -40\text{ °C to }+125\text{ °C}</math></b>						
$t_{pd}$	propagation delay	An to $\bar{Y}_n$ ; see <a href="#">Figure 6</a> <sup>[1]</sup>				
		$V_{CC} = 2.0\text{ V}$	-	-	270	ns
		$V_{CC} = 4.5\text{ V}$	-	-	54	ns
		$V_{CC} = 6.0\text{ V}$	-	-	46	ns
		$\bar{LE}$ to $\bar{Y}_n$ ; see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	285	ns
		$V_{CC} = 4.5\text{ V}$	-	-	57	ns
		$V_{CC} = 6.0\text{ V}$	-	-	48	ns
		$\bar{E}1$ to $\bar{Y}_n$ ; see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	220	ns
		$V_{CC} = 4.5\text{ V}$	-	-	44	ns
		$V_{CC} = 6.0\text{ V}$	-	-	38	ns
		$E2$ to $\bar{Y}_n$ ; see <a href="#">Figure 6</a>				
$V_{CC} = 2.0\text{ V}$	-	-	220	ns		
$V_{CC} = 4.5\text{ V}$	-	-	44	ns		
$V_{CC} = 6.0\text{ V}$	-	-	38	ns		
$t_t$	transition time	see <a href="#">Figure 6</a> <sup>[2]</sup>				
		$V_{CC} = 2.0\text{ V}$	-	-	110	ns
		$V_{CC} = 4.5\text{ V}$	-	-	22	ns
		$V_{CC} = 6.0\text{ V}$	-	-	19	ns
$t_w$	pulse width	$\bar{LE}$ HIGH; see <a href="#">Figure 8</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	75	ns
		$V_{CC} = 4.5\text{ V}$	-	-	15	ns
		$V_{CC} = 6.0\text{ V}$	-	-	13	ns
$t_{su}$	set-up time	An to $\bar{LE}$ ; see <a href="#">Figure 8</a>				
		$V_{CC} = 2.0\text{ V}$	-	-	75	ns
		$V_{CC} = 4.5\text{ V}$	-	-	15	ns
		$V_{CC} = 6.0\text{ V}$	-	-	13	ns

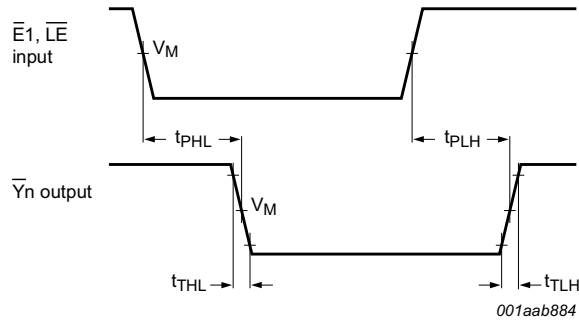
**Table 7. Dynamic characteristics ...continued**  
*GND = 0 V;  $t_r = t_f = 6 \text{ ns}$ ;  $C_L = 50 \text{ pF}$ .*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_h$	hold time	An to $\overline{LE}$ ; see <a href="#">Figure 8</a>				
		$V_{CC} = 2.0 \text{ V}$	-	-	45	ns
		$V_{CC} = 4.5 \text{ V}$	-	-	9	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	8	ns

- [1]  $t_{pd}$  is the same as  $t_{PHL}$ ,  $t_{PLH}$ .
- [2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:  
 $f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $C_L$  = output load capacitance in pF;  
 $V_{CC}$  = supply voltage in V;  
 $N$  = number of inputs switching;  
 $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

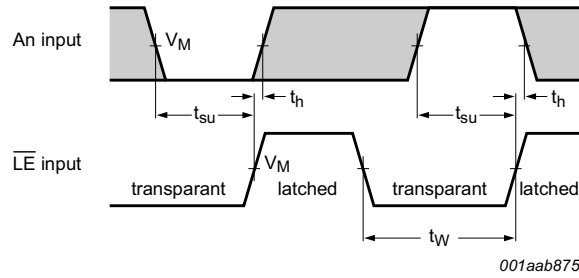
## 11. Waveforms





$V_M = 0.5 \times V_I$ .

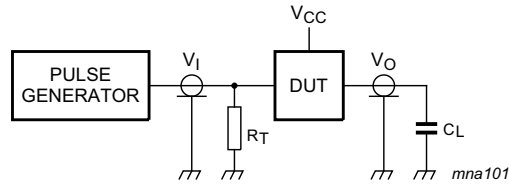
**Fig 7. Waveforms showing the enable input ( $\bar{E}1, \bar{LE}$ ) to output ( $\bar{Y}n$ ) propagation delays and the output transition times**



The shaded areas indicate when the input is permitted to change for predictable output performance.

$V_M = 0.5 \times V_I$ .

**Fig 8. Waveforms showing the data set-up, hold times for  $A_n$  input to  $\bar{LE}$  input and the latch enable pulse width**



Test data is given in [Table 8](#).

Definitions for test circuit:

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

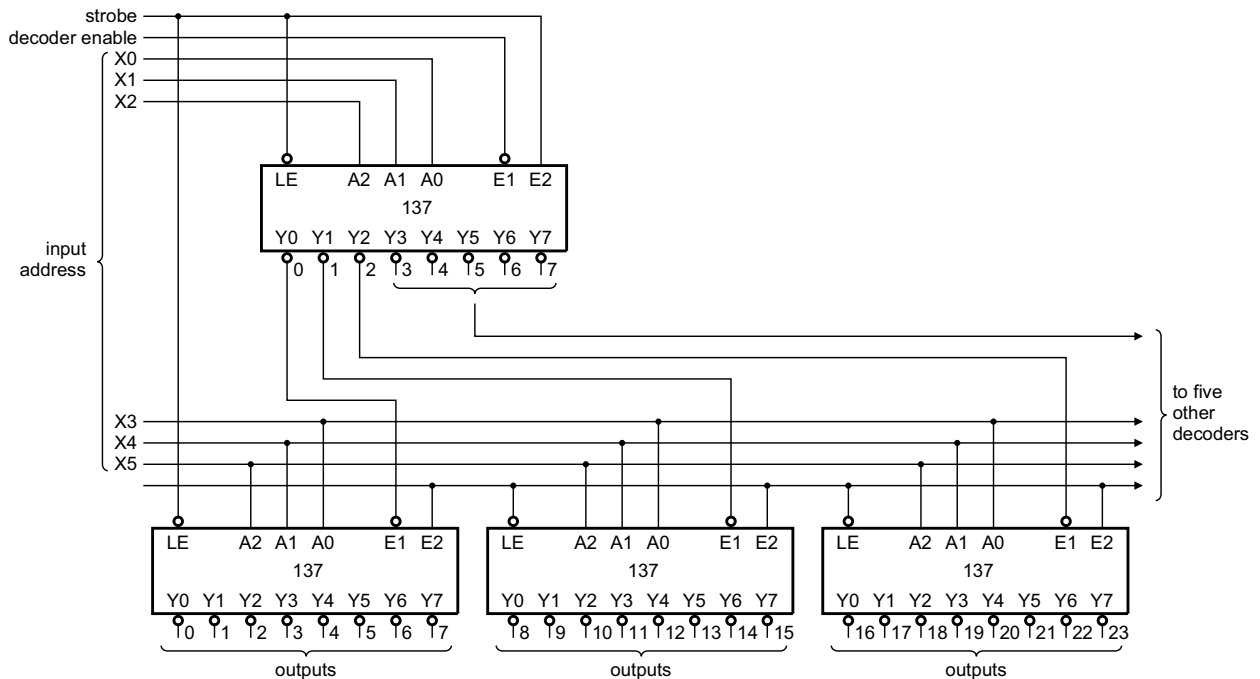
$C_L$  = Load capacitance including jig and probe capacitance.

**Fig 9. Test circuit for measuring switching times**

**Table 8. Test data**

Supply	Input	Load
$V_{CC}$	$V_I$	$C_L$
2.0 V	$V_{CC}$	6 ns
4.5 V	$V_{CC}$	6 ns
6.0 V	$V_{CC}$	6 ns
5.0 V	$V_{CC}$	6 ns

## 12. Application information



001aab885

**Fig 10. 6-to-64 line decoder with input address storage**

13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Fig 11. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



Fig 12. Package outline SOT338-1 (SSOP16)

## 14. Abbreviations

Table 9. Abbreviations

Acronym	Abbreviation
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model

## 15. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC137 v.4	20151223	Product data sheet	-	74HC137 v.3
Modifications:	<ul style="list-style-type: none"> <li>Type numbers 74HC137N (SOT38-4) removed.</li> </ul>			
74HC137 v.3	20041111	Product data sheet	-	74HC_HCT137_CNV v.2
Modifications:	<ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the current presentation and information standard of Philips Semiconductors.</li> <li>Removed type number 74HCT137.</li> <li>Inserted family specification.</li> </ul>			
74HC_HCT137_CNV v.2	19970827	Product specification	-	74HC_HCT137 v.1
74HC_HCT137 v.1	19901201	Product specification	-	-



## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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